

How to Design an Inexpensive HART Transmitter

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ABSTRACT

This application report provides details for designing an inexpensive HART transmitter.

Process measurement and control devices can communicate via the conventional 4- to 20-mA current loop by utilizing the highway addressable remote transducer (HART) protocol. This protocol uses frequency-shift keying (FSK) with the frequencies of 1200 Hz and 2200 Hz. Here one 1200-Hz cycle represents a logic 1, while two 2200-Hz cycles represent a logic 0. Because the average value of the FSK waveform is always zero, the analog 4- to 20-mA signal is not affected.

Ideally, the FSK signal consists of sine waves of the two frequencies superimposed onto the DC measurement signal. However, generating phase-continuous FSK sine waves is a rather complex matter. Therefore, in order to simplify the generation of HART signal waveforms, the physical layer of the HART specification defines parametric limits into which the amplitude, shape, and slew rate of a more generalized waveform must fall. In this case, a trapezoidal waveform, with the limiting values detailed in Figure 1, suits this application well.

PARAMETER	MINIMUM	MAXIMUM	
V _{PP}	0.4 V	0.6 V	
I _{PP}	0.8 mA	1.2 mA	
Slew Rate at 1200 Hz	1 V/ms 2 mA/ms	4 V/ms	
Slew Rate at 2200 Hz	2 V/ms 4 mA/ms	8 mA/ms	





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The HART transmitter in Figure 2 provides a simple and inexpensive solution that generates a trapezoidal HART waveform, superimposes it onto a variable DC level, and subsequently converts the resulting output voltage into the loop current.



Figure 2. Low-Cost HART Transmitter

The HART FSK signal, commonly generated by a local microcontroller unit (MCU), is applied to the input of a first NAND gate, G1. A second output of the MCU's general purpose I/O port serves as an active-high ENABLE signal. G1 controls two further NAND gates, G2 and G3, whose outputs connect together via high-impedance voltage dividers, R_1 and R_2 .

A second voltage divider, consisting of R_4 and R_5 , splits the 5-V supply into a reference voltage of $V_{REF} = VCC/2$, or 2.5 V. As long as ENABLE is low, G2's output is low and G3's output is high. Due to high-impedance loading, the NAND outputs provide rail-to-rail capability; and, with $R_1 = R_2$, the input voltage at A1's non-inverting input, V_{IN} , is also 2.5 V.

When ENABLE is taken high, the outputs of G2 and G3 toggle in phase with each other, thus creating a small square wave at V_{IN} that swings symmetrically about V_{REF} . The peak-to-peak amplitude of V_{IN} is given in Equation 1:

$$V_{\text{IN(PP)}} = V_{\text{S}} \times \frac{R_3}{R_3 + R_1 ||R_2|}$$

(1)

where V_s is the positive 5-V supply, and $R_1 \parallel R_2$ is the parallel combination of R_1 and R_2 .

Inserting the resistor values from Figure 2 into the preceding equation yields an input-voltage swing of $V_{IN(PP)} = 200 \text{ mV}$, making V_{IN} swing between 2.4 and 2.6 V. When V_{IN} rises to 2.6 V, A1's output goes immediately into positive saturation and charges C_3 via R_6 and R_7 . The actual HART voltage on C_3 (V_{HART}) rises linearly until it reaches 2.6 V. At this point, amplifier A1 rapidly exits saturation and acts as a voltage follower, thus holding V_{HART} at 2.6 V. When V_{IN} decreases to 2.4 V, A1's output goes into negative saturation and discharges C_3 via R_6 and R_7 . V_{HART} then ramps down linearly until it reaches 2.4 V, at which point A1 comes out of saturation and again acts as a voltage follower, holding V_{HART} at 2.4 V.

The resulting trapezoidal waveform is equal in amplitude to V_{IN} and swings symmetrically about V_{REF} . Its slew rate is determined by:

$$\frac{dV}{dt} = \frac{I}{C_3} = \frac{\frac{V_{SAT} - V_{HART}}{R_6 + R_7}}{C_3}$$

where V_{SAT} is the positive or negative output-saturation voltage of A1.

(2)



Because the AC content of V_{HART} is small compared to V_{SAT} , V_{HART} can be approximated by its quiescent level, V_{REF} . Also, A1's rail-to-rail-output capability in combination with the high-impedance loading through R_6 yields output saturation levels of 5 V and 0 V. Given that R_7 is much smaller than R_6 , the preceding expression simplifies to:

$$\frac{\mathrm{dV}}{\mathrm{dt}} = \frac{\pm \mathrm{V}_{\mathrm{REF}}}{\mathrm{R}_{6} \times \mathrm{C}_{3}}$$

(3)

If the component values for R_6 and C_3 from Figure 2 are inserted, the trapezoid's slew rate results in ±1.25 V/ms.

Scaling the peak-to-peak amplitude of V_{HART} (200 mV) to a HART peak-to-peak current signal of 1 mA makes the voltage slew rate of 1.25-V/ms equivalent to a current slew rate of 6.25 mA/ms in the HART current signal, which perfectly fits within the given limits of Figure 1.

 R_7 is required to isolate A1's output from the large capacitive load, C_3 , in order to maintain closed-loop stability. The required value depends on A1's unity-gain bandwidth, f_T , and the values of R_6 and C_3 . A good approximation for R_7 is accomplished with:

$$\mathsf{R}_7 \approx \frac{1 + \sqrt{1 + 8\pi \times \mathsf{f}_{\mathsf{T}} \times \mathsf{R}_6 \times \mathsf{C}_3}}{2\pi \times \mathsf{f}_{\mathsf{T}} \times \mathsf{C}_3} \tag{4}$$

A1 must have a reasonably wide frequency response and be able to slew significantly faster than the HART trapezoid. The OPA2374, a low-cost dual operational amplifier from Texas Instruments (TI), provides a sufficiently fast slew rate of 5 V/ μ s and a unity-gain bandwidth of f_T = 6.5 MHz. In addition, the amplifier outputs have rail-to-rail drive capability with a typical quiescent current of 585 μ A per amplifier.

The second amplifier, A2, superimposes the HART signal onto a variable DC voltage, V_{DC} . The voltage at A2's output, V_{OUT} , becomes:

$$V_{OUT} = \left(V_{REF} \times \frac{R_{10}}{R_9 + R_{10}} + V_{DC} \times \frac{R_9}{R_9 + R_{10}} \right) \\ \times \left(1 + \frac{R_{11}}{R_8} \right) - V_{HART} \times \frac{R_{11}}{R_8}$$
(5)

Making R_8 to R_{11} equal in value simplifies this equation to:

$$V_{OUT} = V_{REF} + V_{DC} - V_{HART}$$

Because V_{HART} consists of a 200-mV trapezoid swinging symmetrically about V_{REF} , the output of A2 contains only the small HART waveform riding on the variable DC level. Feeding V_{OUT} into TI's XTR115 voltage-to-current converter makes each 200 mV of V_{DC} equivalent to 1 mA of current. Thus, varying V_{DC} from 0.8 V to 4.0 V is equivalent to a 4- to 20-mA current range.

Resistors R₈ to R₁₁ should be large enough to minimize the loading effects on C₃'s charging current but not so large as to introduce errors through A2's input-offset current. Well-matched resistor values remove V_{REF} entirely from V_{OUT} so that $V_{OUT} = V_{DC} \pm 100$ mV. Therefore, a mismatch in R₄ and R₅ or variations in the voltage supply have little effect on V_{OUT} 's DC content.

The XTR115 is a two-wire, precision, current-output converter that transmits analog 4- to 20-mA signals over an industry-standard current loop. The device provides accurate current scaling as well as functions for limiting output current. Its on-chip 5-V voltage regulator is used to power the external circuitry. To ensure control of the output current, I_{OUT} , the current-return pin, I_{RET} , serves as a local ground and senses any current used in the external circuitry. Its input stage has a current gain of 100, which is set by the two laser-trimmed gain resistors, R_{G1} and R_{G2} :

$$Gain = 1 + \frac{R_{G1}}{R_{G2}}$$

(7)

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(6)

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Therefore, an input current, I_{IN} , produces an output current, I_{OUT} , equal to $I_{IN} \times 100$. With the voltage potential at I_{IN} being 0 (referenced to I_{RET}), the resistor value required to convert an input voltage into a defined output current is calculated with:

$$R_{IN} = \frac{V_{IN}}{I_{IN}} = \frac{V_{IN}}{I_{OUT}} \times Gain$$
(8)

Converting the 200-mV $_{\mbox{\tiny PP}}$ HART voltage into a 1-mA current thus requires an input resistance of:

$$R_{IN} = \frac{200 \text{ mV}}{1 \text{ mA}} \times 100 = 20 \text{ k}\Omega$$
(9)

In addition, R_{IN} defines the input-voltage range for a 4- to 20-mA current range with:

$$V_{DC_min} = \frac{R_{IN} \times I_{OUT_min}}{Gain} = \frac{20 \text{ k}\Omega \times 4 \text{ mA}}{100} = 0.8 \text{ V}$$
(10)

and

$$V_{DC_max} = \frac{R_{IN} \times I_{OUT_max}}{Gain} = \frac{20 \text{ k}\Omega \times 20 \text{ mA}}{100} = 4 \text{ V}$$
(11)

Conclusion

Simple operational-amplifier circuits can be used to design a low-cost HART transmitter for the conventional 4- to 20-mA current loop.

Figure 3 shows the signal voltages at various test points during a HART transmission for a DC input of 2 V. Resistor matching in the difference amplifier, A2, removes the V_{REF} component in the output signal. Thus, deviations in the reference voltage have no impact on V_{OUT} . The output signal therefore swings symmetrically around the 2-V DC input.



Figure 3. Signal Voltages of the HART Transmitter's Signal Path



References

For more information related to this article, download an Acrobat® Reader® file at www.ti.com/lit/litnumber and replace "litnumber" with the TI Lit. # for the following materials:

- 1. Texas Instruments. (2012, Mar. 9). Industrial automation solutions: Sensors and field transmitters SLYB177E
- 2. Jerald G. Graeme, Optimizing Op Amp Performance, 1st ed. New York: McGraw-Hill Professional, Dec. 1, 1996.

Related Web sites

interface.ti.com www.ti.com/product/partnumber. Replace partnumber with OPA2374, SN74AHC00, or XTR115.

Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from	Original	(October 2012) to A Revision
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